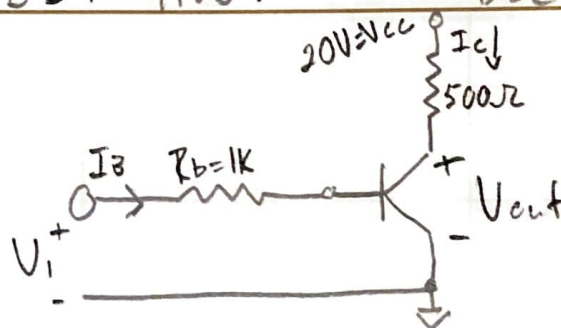


1.) a) $V_i = 0.2V$

$I_c = 0A$

$V_{out} = 20V$



b.) $V_i = 3V$ saturated

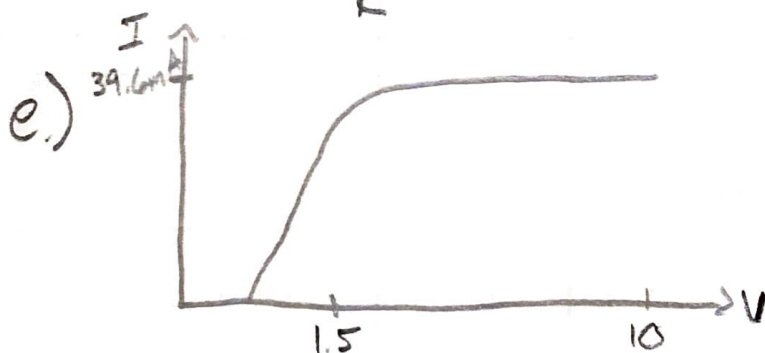
$V_{out} = V_{CEsat} = 0.2V$

$$I_c = \frac{V_{cc} - V_{CEsat}}{R} = \frac{20 - 0.2}{500} = 39.6mA$$

c.) $V_i = 8V$ saturated

$V_{out} = 0.2V$

$$I_c = \frac{V_{cc} - V_{CEsat}}{R} = 39.6mA$$



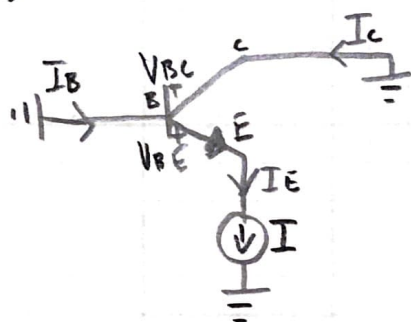
2.) a.) Label collector, base, emitter, terminals (C, B, E)

b.) Transistor type: NPN

c.) Label V_{BE} & V_{BC} and directions for I_E, I_C, I_B

d.) find $I_E, I_C, I_B, V_{BC}, V_{BE}$ if $I = 175mA$

2)



$$I_E = I = 175 \text{ mA}$$

$$I_B + I_C = I_E \Rightarrow I_C = \beta I_B$$

$$I_B + \beta I_B = I_E \Rightarrow I_B (1 + \beta)$$

$$I_B = \frac{175}{101} = 1.73 \text{ mA}$$

$$I_C = I_E - I_B$$

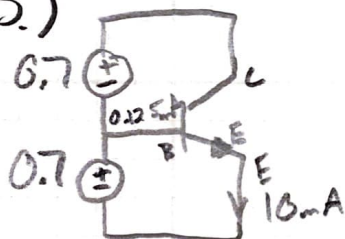
$$= 175 - 1.73 = 173.27 \text{ mA}$$

$$V_{BC} = 0 \rightarrow \text{GND}$$

$$V_{BE} = \phi_T \ln\left(\frac{I_C}{I_S}\right) = 0.0258 \ln\left(\frac{173.27}{6 \times 10^{-16}}\right)$$

$$\Rightarrow V_{BE} = 0.681 \text{ V}$$

3)

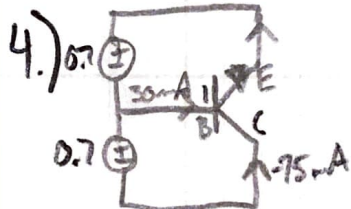


$$I_C + I_B = I_E \rightarrow I_C = I_E - I_B = I_C = 10 \text{ mA} - 0.125 \text{ mA} = 9.875 \text{ mA}$$

$$I_C = \beta I_B \rightarrow \beta = \frac{I_C}{I_B}$$

$$\beta = 79$$

$$V_{BE} = \phi_T \ln\left(\frac{I_C}{I_S}\right) \Rightarrow e^{\left(\frac{V_{BE}}{\phi_T}\right)} = \frac{I_C}{I_S} \quad I_S = \frac{I_C}{e^{\left(\frac{V_{BE}}{\phi_T}\right)}} = 1.63 \times 10^{-14} \text{ A}$$



$$I_B + I_C = I_E$$

$$30 - 75 = I_E \Rightarrow -45 \text{ mA}$$

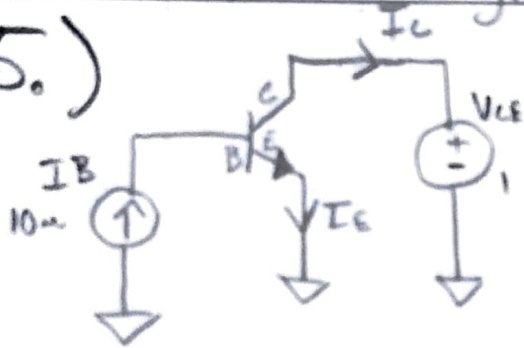
$$-\left(\frac{-75}{30}\right) - 1 = \beta \Rightarrow \beta = 1.5$$

$$-I_C = (\beta + 1) I_B$$

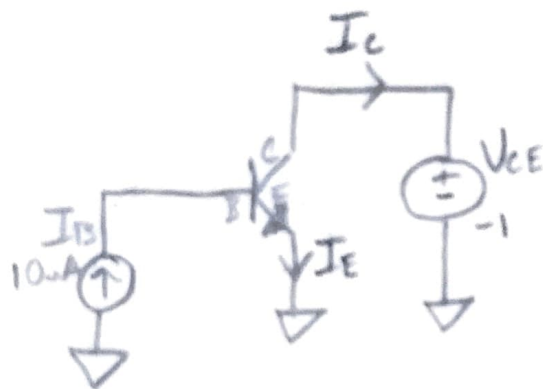
$$V_{BC} = \phi_T \ln\left(\frac{I_E}{I_S}\right) \rightarrow \frac{I_E}{e^{\left(\frac{V_{BC}}{\phi_T}\right)}} = I_S = 7.4136 \times 10^{-17} \text{ A}$$

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5.)



$$\begin{aligned} I_E &= -510\mu\text{A} \\ I_C &= 500\mu\text{A} \\ I_B &= 10\mu\text{A} \end{aligned}$$



$$\begin{aligned} I_B &= 10\mu\text{A} \\ I_C &= 500\mu\text{A} \\ I_E &= -510\mu\text{A} \end{aligned}$$

BJT HW1

